

Fig. 1

WO 00/38406

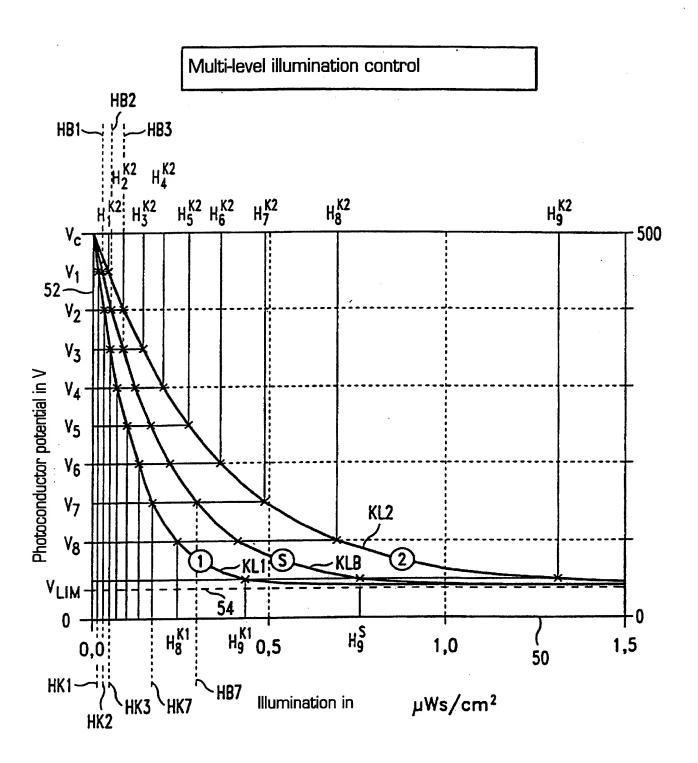


Fig.2

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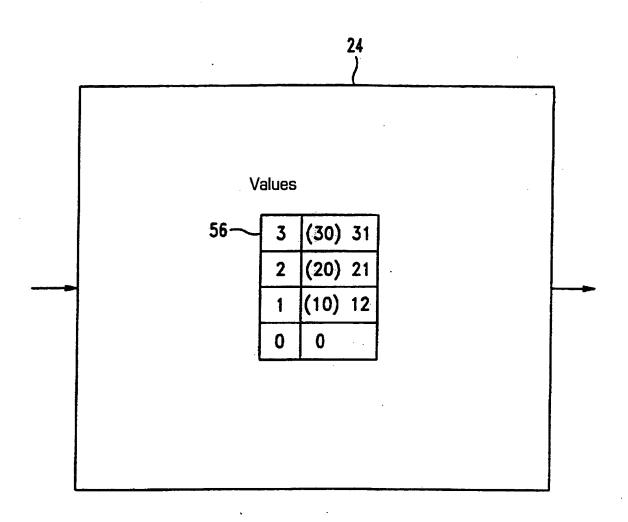


Fig.3

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$$V_{D}(K,T,H) = (V_{C}-V_{LIM}) \cdot exp(-K \cdot T \cdot H) + V_{LIM}$$
 [1]

$$K(V_D, T, H) = \frac{1}{T \cdot H} \cdot \ln \left(\frac{V_C - V_{LIM}}{V_D - V_{LIM}} \right)$$
 [2]

$$H(V_D, K, T) = \frac{1}{T \cdot K} \cdot \ln \left(\frac{V_C - V_{LIM}}{V_D - V_{LIM}} \right)$$
 [3]

with:

 V_{C} : photoconductor charge potential in V

 V_{n} : photoconductor discharge potential in V

 $V_{\mbox{\scriptsize LIM}}$: lowest obtainable discharge potential in V

H: illumination in μWs/cm²

T: photoconductor temperature in °C

K: photoconductor sensitivity factor in $cm^2/(\mu Ws ^{\circ}C)$

Fig.4

Multi-level control - adaptation of the charge height

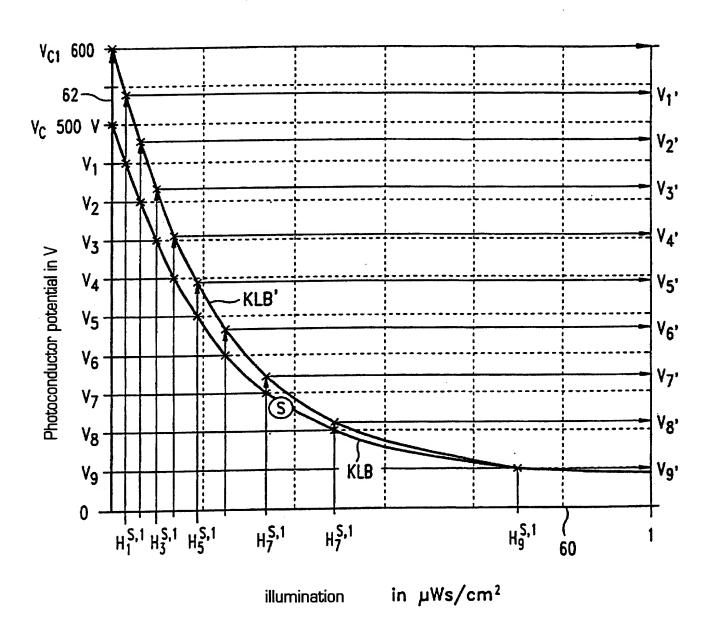


Fig.5

